

DATA SHEET



TEA5767HN

Low-power FM stereo radio for
handheld applications

Preliminary specification

2002 Sep 13

Low-power FM stereo radio for handheld applications

TEA5767HN

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1 FEATURES

- High sensitivity due to integrated low-noise RF input amplifier
- FM mixer for conversion to IF of the US/Europe (87.5 to 108 MHz) and Japanese (76 to 91MHz) FM band
- Preset tuning to receive Japanese TV audio up to 108 MHz
- RF Automatic Gain Control (AGC) circuit
- LC tuner oscillator operating with low cost fixed chip inductors
- FM IF selectivity performed internally
- No external discriminator needed due to fully integrated FM demodulator
- Crystal reference frequency oscillator; the oscillator operates with a 32.768 kHz clock crystal or with a 13 MHz crystal and with an externally applied 6.5 MHz reference frequency
- PLL synthesizer tuning system
- I²C-bus and 3-wire bus, selectable via pin BUSMODE
- 7-bit IF counter output via the bus
- 4-bit level information output via the bus
- Soft mute
- Signal dependent mono to stereo blend [Stereo Noise Cancelling (SNC)]
- Signal dependent High Cut Control (HCC)
- Soft mute, SNC and HCC can be switched off via the bus
- Adjustment-free stereo decoder
- Autonomous search tuning function
- Standby mode
- Two software programmable ports
- Bus enable line to switch the bus input and output lines into 3-state mode
- Automotive temperature range (at V_{CCA}, V_{CC(VCO)} and V_{CCD} = 5 V).



2 GENERAL DESCRIPTION

The TEA5767HN is a single-chip electronically tuned FM stereo radio for low-voltage application with fully integrated IF selectivity and demodulation. The radio is completely adjustment-free and only requires a minimum of small and low cost external components. The radio can be tuned to the European, US and Japanese FM bands.

3 ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TEA5767HN	HVQFN40	plastic, heatsink very thin quad flat package; no leads; 40 terminals; body 6 × 6 × 0.85 mm	SOT618-1

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4 QUICK REFERENCE DATA

$$V_{CCA} = V_{CC(VCO)} = V_{CCD}$$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CCA}	analog supply voltage		2.5	3.0	5.0	V
V _{CC(VCO)}	voltage controlled oscillator supply voltage		2.5	3.0	5.0	V
V _{CCD}	digital supply voltage		2.5	3.0	5.0	V
I _{CCA}	analog supply current	operating; V _{CCA} = 3 V	6.0	8.4	10.5	mA
		standby mode; V _{CCA} = 3 V	–	3	6	μA
I _{CC(VCO)}	voltage controlled oscillator supply current	operating; V _{VCOTANK1} = V _{VCOTANK2} = 3 V	560	750	940	μA
		standby mode; V _{VCOTANK1} = V _{VCOTANK2} = 3 V	–	1	2	μA
I _{CCD}	digital supply current	operating; V _{CCD} = 3 V	2.1	3.0	3.9	mA
		standby mode; V _{CCD} = 3 V				
		bus enable line HIGH	30	56	80	μA
		bus enable line LOW	11	19	26	μA
f _{FM(ant)}	FM input frequency		76	–	108	MHz
T _{amb}	ambient temperature	V _{CCA} = V _{CC(VCO)} = V _{CCD} = 2.5 V	–10	–	+75	°C
		V _{CCA} = V _{CC(VCO)} = V _{CCD} = 5 V	–40	–	+85	°C
FM overall system parameters; see Fig.7						
V _{RF}	RF sensitivity input voltage	f _{RF} = 76 to 108 MHz; Δf = 22.5 kHz; f _{mod} = 1 kHz; (S+N)/N = 26 dB; de-emphasis = 75 μs; L = R; B _{AF} = 300 Hz to 15 kHz	–	2	3.5	μV
S _{–200}	LOW side 200 kHz selectivity	Δf = –200 kHz; f _{RF} = 76 to 108 MHz; note 1	32	36	–	dB
S ₊₂₀₀	HIGH side 200 kHz selectivity	Δf = +200 kHz; f _{RF} = 76 to 108 MHz; note 1	39	43	–	dB
V _{AFL} ; V _{AFR}	left and right audio frequency output voltage	V _{RF} = 1 mV; L = R; Δf = 22.5 kHz; f _{mod} = 1 kHz; de-emphasis = 75 μs	60	75	90	mV
(S+N)/N	maximum signal plus noise-to-noise ratio	V _{RF} = 1 mV; L = R; Δf = 22.5 kHz; f _{mod} = 1 kHz; de-emphasis = 75 μs; B _{AF} = 300 Hz to 15 kHz	54	60	–	dB
α _{cs(stereo)}	stereo channel separation	V _{RF} = 1 mV; R = L = 0 or R = 0 and L = 1 including 9% pilot; Δf = 75 kHz; f _{mod} = 1 kHz; data byte 3 bit 3 = 0; data byte 4 bit 1 = 1	24	30	–	dB
THD	total harmonic distortion	V _{RF} = 1 mV; L = R; Δf = 75 kHz; f _{mod} = 1 kHz; de-emphasis = 75 μs	–	0.4	1	%

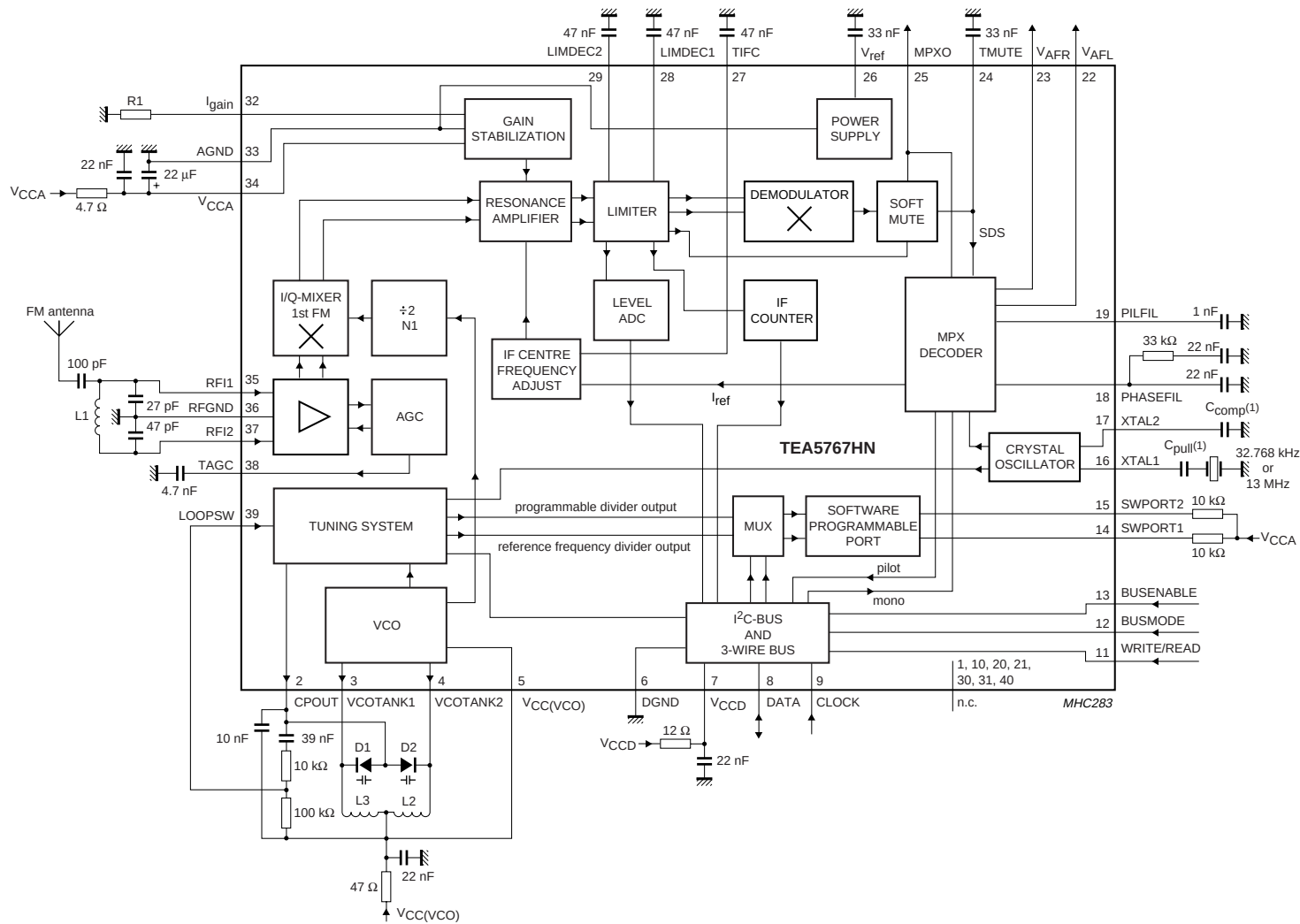
Note

1. LOW side and HIGH side selectivity can be switched by changing the mixer from HIGH side to LOW side LO injection.

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5 BLOCK DIAGRAM



The component list is given in Chapter 14.

(1) C_{comp} and C_{pull} data depends on crystal specification.

Fig.1 Block diagram.

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6 PINNING

SYMBOL	PIN	DESCRIPTION
n.c.	1	not connected
CPOUT	2	charge pump output of synthesizer PLL
VCOTANK1	3	voltage controlled oscillator tuned circuit output 1
VCOTANK2	4	voltage controlled oscillator tuned circuit output 2
V _{CC(VCO)}	5	voltage controlled oscillator supply voltage
DGND	6	digital ground
V _{CCD}	7	digital supply voltage
DATA	8	bus data line input/output
CLOCK	9	bus clock line input
n.c.	10	not connected
WRITE/READ	11	write/read control input for the 3-wire bus
BUSMODE	12	bus mode select input
BUSENABLE	13	bus enable input
SWPORT1	14	software programmable port 1
SWPORT2	15	software programmable port 2
XTAL1	16	crystal oscillator input 1
XTAL2	17	crystal oscillator input 2
PHASEFIL	18	phase detector loop filter
PILFIL	19	pilot detector low-pass filter
n.c.	20	not connected
n.c.	21	not connected
V _{AFL}	22	left audio frequency output voltage
V _{AFR}	23	right audio frequency output voltage
TMUTE	24	time constant for soft mute
MPXO	25	FM demodulator MPX signal output
V _{ref}	26	reference voltage
TIFC	27	time constant for IF centre adjust
LIMDEC1	28	decoupling IF limiter 1
LIMDEC2	29	decoupling IF limiter 2
n.c.	30	not connected
n.c.	31	not connected
I _{gain}	32	gain control current for IF filter
AGND	33	analog ground
V _{CCA}	34	analog supply voltage
RFI1	35	RF input 1
RFGND	36	RF ground
RFI2	37	RF input 2
TAGC	38	time constant RF AGC
LOOPSW	39	switch output of synthesizer PLL loop filter
n.c.	40	not connected

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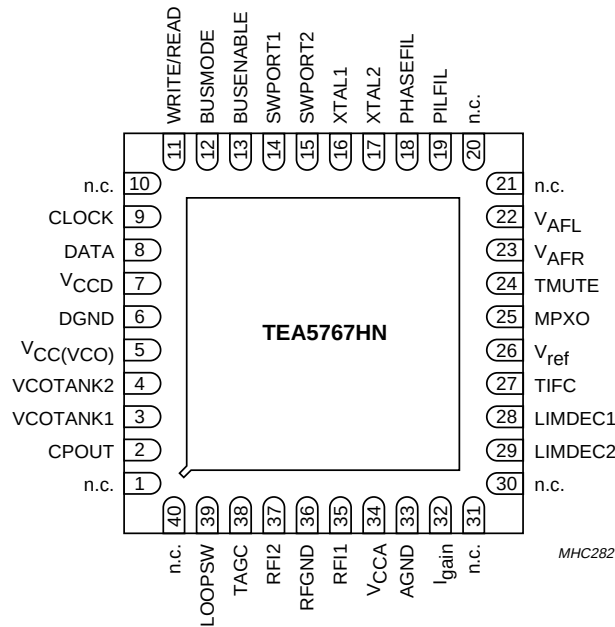


Fig.2 Pin configuration (bottom view).

7 FUNCTIONAL DESCRIPTION

7.1 Low-noise RF amplifier

The LNA input impedance together with the LC RF input circuit defines an FM band filter. The gain of the LNA is controlled by the RF AGC circuit.

7.2 FM mixer

The FM quadrature mixer converts the FM RF (76 to 108 MHz) to an IF of 225 kHz.

7.3 VCO

The varactor tuned LC VCO provides the Local Oscillator (LO) signal for the FM quadrature mixer. The VCO frequency range is 150 to 217 MHz.

7.4 Crystal oscillator

The crystal oscillator can operate with a 32.768 kHz clock crystal or a 13 MHz crystal. The temperature drift of standard 32.768 kHz clock crystals limits the operational temperature range from -10 to +60 °C.

The PLL synthesizer can be clocked externally with a 32.768 kHz, a 6.5 MHz or a 13 MHz signal via pin XTAL2.

The crystal oscillator generates the reference frequency for:

- The reference frequency divider for the synthesizer PLL
- The timing for the IF counter
- The free-running frequency adjustment of the stereo decoder VCO
- The centre frequency adjustment of the IF filters.

7.5 PLL tuning system

The PLL synthesizer tuning system is suitable to operate with a 32.768 kHz or a 13 MHz reference frequency generated by the crystal oscillator or applied to the IC from an external source. The synthesizer can also be clocked via pin XTAL2 at 6.5 MHz. The PLL tuning system can perform an autonomous search tuning function.

7.6 RF AGC

The RF AGC prevents overloading and limits the amount of intermodulation products created by strong adjacent channels.

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7.7 IF filter

Fully integrated IF filter.

7.8 FM demodulator

The FM quadrature demodulator has an integrated resonator to perform the phase shift of the IF signal.

7.9 Level voltage generator and analog-to-digital converter

The FM IF analog level voltage is converted to 4 bits digital data and output via the bus.

7.10 IF counter

The IF counter outputs a 7-bit count result via the bus.

7.11 Soft mute

The low-pass filtered level voltage drives the soft mute attenuator at low RF input levels. The soft mute function can be switched off via the bus.

7.12 MPX decoder

The PLL stereo decoder is adjustment-free. The stereo decoder can be switched to mono via the bus.

7.13 Signal dependent mono to stereo blend

With a decreasing RF input level the MPX decoder blends from stereo to mono to limit the output noise. The continuous mono to stereo blend can also be programmed via the bus to an RF level depending switched mono to stereo transition. Stereo Noise Cancelling (SNC) can be switched off via the bus.

7.14 Signal dependent AF response

The audio bandwidth will be reduced with a decreasing RF input level. The function can be switched off via the bus.

7.15 Software programmable ports

Two software programmable ports (open-collector) can be addressed via the bus.

The port 1 (pin SWPORT1) function can be changed with write data byte 4 bit 0 (see Table 13). Pin SWPORT1 is then output for the ready flag of read byte 1.

7.16 I²C-bus and 3-wire bus

The 3-wire bus operates with a maximum clock frequency of 1 MHz.

The I²C-bus operates with a maximum clock frequency of 400 kHz.

The I²C-bus mode is selected when pin BUSMODE is LOW, when pin BUSMODE is HIGH the 3-wire bus mode is selected.

8 I²C-BUS, 3-WIRE BUS AND BUS-CONTROLLED FUNCTIONS

8.1 I²C-bus specification

Information about the I²C-bus can be found in the brochure *"The I²C-bus and how to use it"* (order number 9398 393 40011).

The standard I²C-bus specification is expanded by the following definitions.

IC address C0: 1100000.

Structure of the I²C-bus logic: slave transceiver.

Subaddresses are not used.

The maximum LOW-level input and the minimum HIGH-level input are specified to 0.2V_{CCD} and 0.45V_{CCD} respectively.

The pin BUSMODE must be connected to ground to operate the IC with the I²C-bus.

Note: The bus operates at a maximum clock frequency of 400 kHz. It is not allowed to connect the IC to a bus operating at a higher clock rate.

8.1.1 DATA TRANSFER

Data sequence: address, byte 1, byte 2, byte 3, byte 4 and byte 5 (the data transfer has to be in this order). The LSB = 0 of the address indicates a WRITE operation to the TEA5767HN.

Bit 7 of each byte is considered as the MSB and has to be transferred as the first bit of the byte.

The data becomes valid bitwise at the appropriate falling edge of the clock. A STOP condition after any byte can shorten transmission times.

When writing to the transceiver by using the STOP condition before completion of the whole transfer:

- The remaining bytes will contain the old information
- If the transfer of a byte is not completed, the new bits will be used, but a new tuning cycle will not be started.

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The IC can be switched into a low current standby mode with the standby bit; the bus is then still active. The standby current can be reduced by deactivating the bus interface (pin BUSENABLE LOW). If the bus interface is deactivated (pin BUSENABLE LOW) without the standby mode being programmed, the IC maintains normal operation, but is isolated from the bus lines.

The software programmable output (SWPORT1) can be programmed to operate as a tuning indicator output. As long as the IC has not completed a tuning action, pin SWPORT1 remains LOW. The pin becomes HIGH, when a preset or search tuning is completed or when a band limit is reached.

The reference frequency divider of the synthesizer PLL is changed when the MSB in byte 5 is set to logic 1. The tuning system can then be clocked via pin XTAL2 at 6.5 MHz.

8.1.2 POWER-ON RESET

At Power-on reset the mute is set, all other bits are set to LOW. To initialize the IC all bytes have to be transferred.

8.2 I²C-bus protocol

Table 1 Write mode

S ⁽¹⁾	address (write)	A ⁽²⁾	data byte(s)	A ⁽²⁾	P ⁽³⁾
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Notes

1. S = START condition.
2. A = acknowledge.
3. P = STOP condition.

Table 2 Read mode

S ⁽¹⁾	address (read)	A ⁽²⁾	data byte 1
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Notes

1. S = START condition.
2. A = acknowledge.

Table 3 IC address byte

IC ADDRESS						MODE
1	1	0	0	0	0	R/W ⁽¹⁾

Note

1. Read or write mode:
 - a) 0 = write operation to the TEA5767HN
 - b) 1 = read operation from the TEA5767HN.

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8.3 3-wire bus specification

The 3-wire bus controls the write/read, clock and data lines and operates at a maximum clock frequency of 1 MHz.

Hint: By using the standby bit the IC can be switched into a low current standby mode. In standby mode the IC must be in the WRITE mode. When the IC is switched to READ mode, during standby, the IC will hold the data line down. The standby current can be reduced by deactivating the bus interface (pin BUSENABLE LOW). If the bus interface is deactivated (pin BUSENABLE LOW) without the standby mode being programmed, the IC maintains normal operation, but is isolated from the clock and data line.

8.3.1 DATA TRANSFER

Data sequence: byte 1, byte 2, byte 3, byte 4 and byte 5 (the data transfer has to be in this order).

A positive edge at pin WRITE/READ enables the data transfer into the IC. The data has to be stable at the positive edge of the clock. Data may change while the clock is LOW and is written into the IC on the positive edge of the clock. Data transfer can be stopped after the transmission of new tuning information with the first two bytes or after each following byte.

A negative edge at pin WRITE/READ enables the data transfer from the IC. The WRITE/READ pin changes while the clock is LOW. With the negative edge at pin WRITE/READ the MSB of the first byte occurs at pin DATA. The bits are shifted on the negative clock edge to pin DATA and can be read on the positive edge.

To do two consecutive read or write actions, pin WRITE/READ has to be toggled for at least one clock period. When a search tuning request is sent, the IC autonomously starts searching the FM band; the search direction and search stop level can be selected. When a station with a field-strength equal to or greater than the stop level is found, the tuning system stops and the ready flag bit is set to HIGH. When, during search, a band limit is reached, the tuning system stops at the band limit and the band limit flag bit is set to HIGH. The ready flag is also set to HIGH in this case.

The software programmable output (SWPORT1) can be programmed to operate as a tuning indicator output. As long as the IC has not completed a tuning action pin SWPORT1 remains LOW. The pin becomes HIGH, when a preset or search tuning is completed or when a band limit is reached.

The reference frequency divider of the synthesizer PLL is changed when the MSB in byte 5 is set to logic 1. The tuning system can then be clocked via pin XTAL2 at 6.5 MHz.

8.3.2 POWER-ON RESET

At Power-on reset the mute is set, all other bits are random. To initialize the IC all bytes have to be transferred.

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8.4 Writing data

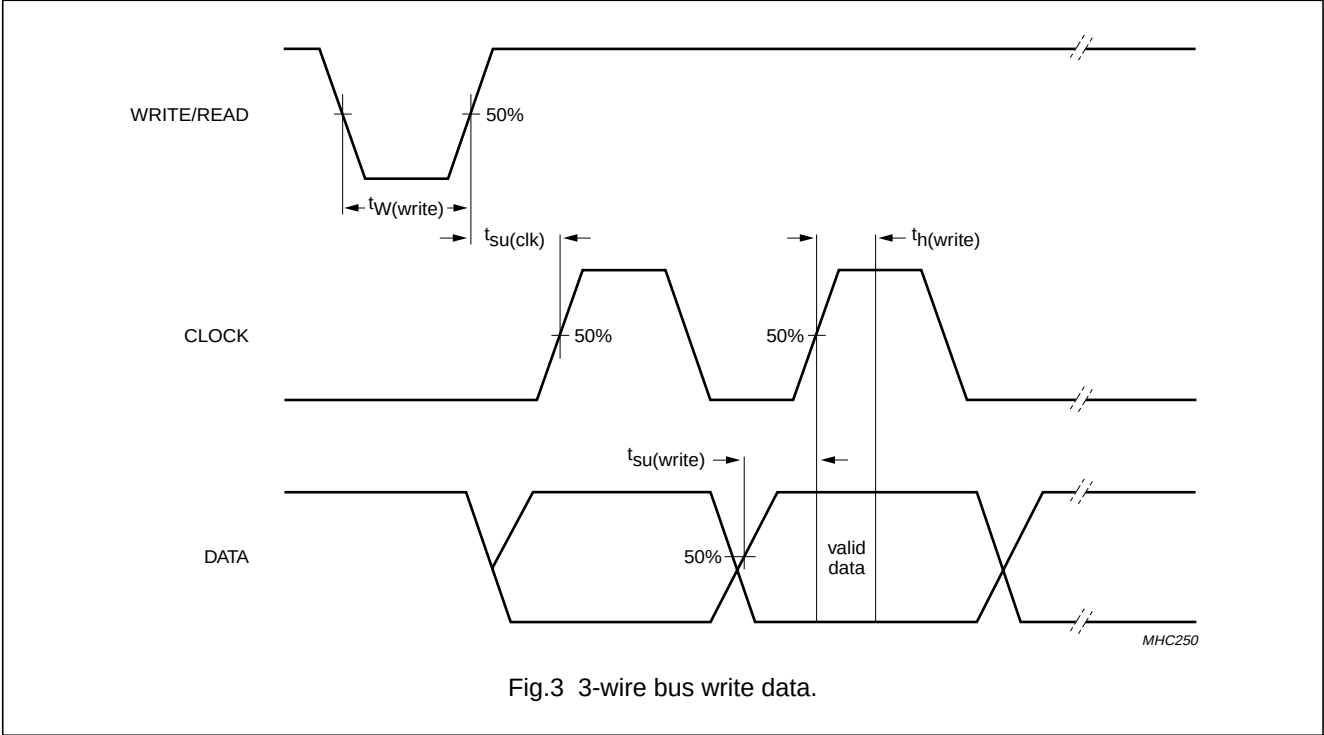


Table 4 Write mode

DATA BYTE 1	DATA BYTE 2	DATA BYTE 3	DATA BYTE 4	DATA BYTE 5
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Table 5 Format of 1st data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
MUTE	SM	PLL13	PLL12	PLL11	PLL10	PLL9	PLL8

Table 6 Description of 1st data byte bits

BIT	SYMBOL	DESCRIPTION
7	MUTE	if MUTE = 1 then L and R audio are muted; if MUTE = 0 then L and R audio are not muted
6	SM	Search Mode: if SM = 1 then in search mode; if SM = 0 then not in search mode
5 to 0	PLL[13:8]	setting of synthesizer programmable counter for search or preset

Table 7 Format of 2nd data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
PLL7	PLL6	PLL5	PLL4	PLL3	PLL2	PLL1	PLL0

Table 8 Description of 2nd data byte bits

BIT	SYMBOL	DESCRIPTION
7 to 0	PLL[7:0]	setting of synthesizer programmable counter for search or preset

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Table 9 Format of 3rd data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
SUD	SSL1	SSL0	HLSI	MS	ML	MR	SWP1

Table 10 Description of 3rd data byte bits

BIT	SYMBOL	DESCRIPTION
7	SUD	Search Up/Down: if SUD = 1 then search up; if SUD = 0 then search down
6 and 5	SSL[1:0]	Search Stop Level: see Table 11
4	HLSI	HIGH/LOW Side Injection: if HLSI = 1 then HIGH side LO injection; if HLSI = 0 then LOW side LO injection
3	MS	Mono to Stereo: if MS = 1 then forced mono; if MS = 0 then stereo ON
2	ML	Mute Left: if ML = 1 then the left audio channel is muted and forced mono; if ML = 0 then the left audio channel is not muted
1	MR	Mute Right: if MR = 1 then the right audio channel is muted and forced mono; if MR = 0 then the right audio channel is not muted
0	SWP1	Software programmable port 1: if SWP1 = 1 then port 1 is HIGH; if SWP1 = 0 then port 1 is LOW

Table 11 Search stop level setting

SSL1	SSL0	SEARCH STOP LEVEL
0	0	not allowed in search mode
0	1	low; level ADC output = 5
1	0	mid; level ADC output = 7
1	1	high; level ADC output = 10

Table 12 Format of 4th data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
SWP2	STBY	BL	XTAL	SMUTE	HCC	SNC	SI

Table 13 Description of 4th data byte bits

BIT	SYMBOL	DESCRIPTION
7	SWP2	Software programmable port 2: if SWP2 = 1 then port 2 is HIGH; if SWP2 = 0 then port 2 is LOW
6	STBY	Standby: if STBY = 1 then in standby mode; if STBY = 0 then not in standby mode
5	BL	Band Limits: if BL = 1 then Japanese FM band; if BL = 0 then US/Europe FM band
4	XTAL	if XTAL = 1 then $f_{xtal} = 32.768$ kHz; if XTAL = 0 then $f_{xtal} = 13$ MHz
3	SMUTE	Soft MUTE: if SMUTE = 1 then soft mute is ON; if SMUTE = 0 then soft mute is OFF
2	HCC	High Cut Control: if HCC = 1 then high cut control is ON; if HCC = 0 then high cut control is OFF
1	SNC	Stereo Noise Cancelling: if SNC = 1 then stereo noise cancelling is ON; if SNC = 0 then stereo noise cancelling is OFF
0	SI	Search Indicator: if SI = 1 then pin SWPORT1 is output for the ready flag; if SI = 0 then pin SWPORT1 is software programmable port 1

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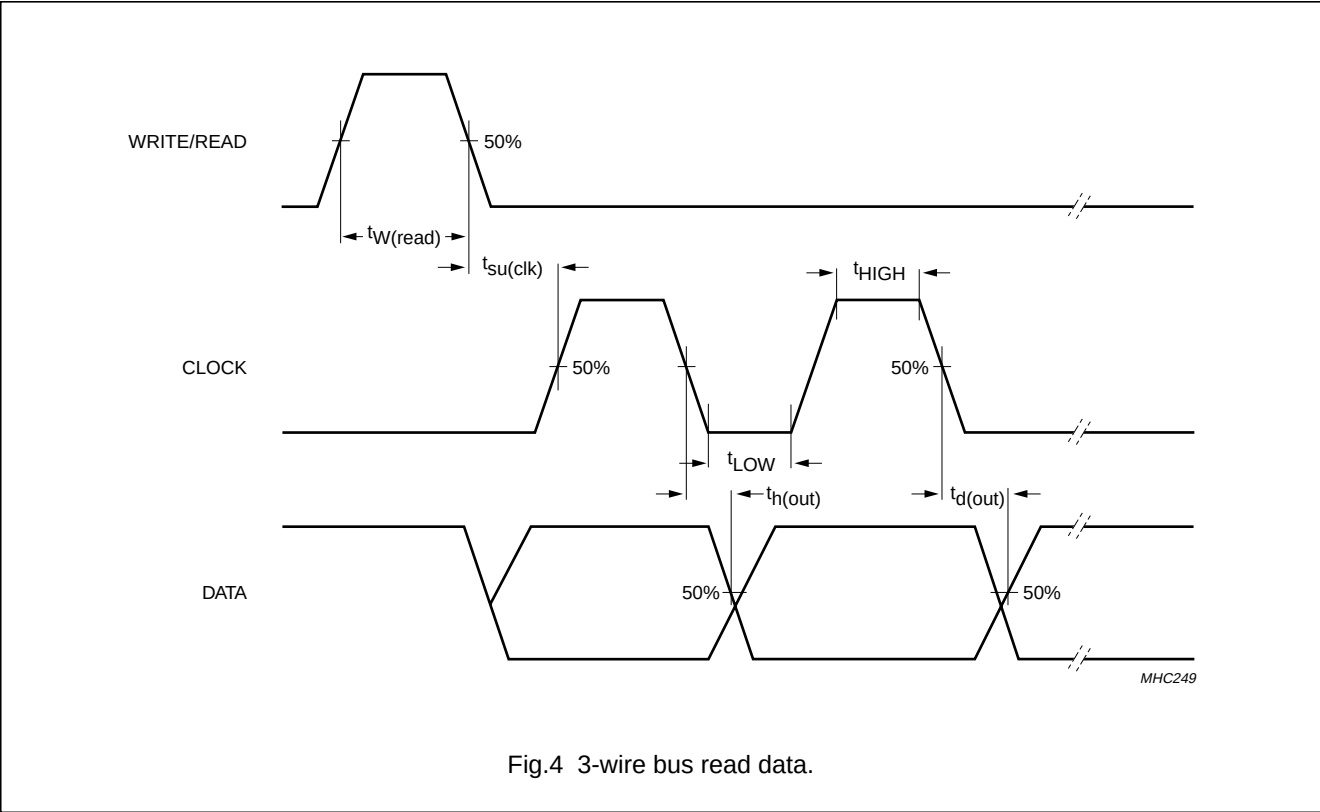
Table 14 Format of 5th data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
PLLREF	DTC	–	–	–	–	–	–

Table 15 Description of 5th data byte bits

BIT	SYMBOL	DESCRIPTION
7	PLLREF	if PLLREF = 1 then the 6.5 MHz reference frequency for the PLL is enabled; if PLLREF = 0 then the 6.5 MHz reference frequency for the PLL is disabled
6	DTC	if DTC = 1 then the de-emphasis time constant is 75 µs; if DTC = 0 then the de-emphasis time constant is 50 µs
5 to 0	–	not used; position is don't care

8.5 Reading data



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Table 16 Read mode

DATA BYTE 1	DATA BYTE 2	DATA BYTE 3	DATA BYTE 4	DATA BYTE 5
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Table 17 Format of 1st data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
RF	BLF	PLL13	PLL12	PLL11	PLL10	PLL9	PLL8

Table 18 Description of 1st data byte bits

BIT	SYMBOL	DESCRIPTION
7	RF	Ready Flag: if RF = 1 then a station has been found or the band limit has been reached; if RF = 0 then no station has been found
6	BLF	Band Limit Flag: if BLF = 1 then the band limit has been reached; if BLF = 0 then the band limit has not been reached
5 to 0	PLL[13:8]	setting of synthesizer programmable counter after search or preset

Table 19 Format of 2nd data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
PLL7	PLL6	PLL5	PLL4	PLL3	PLL2	PLL1	PLL0

Table 20 Description of 2nd data byte bits

BIT	SYMBOL	DESCRIPTION
7 to 0	PLL[7:0]	setting of synthesizer programmable counter after search or preset

Table 21 Format of 3rd data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
STEREO	IF6	IF5	IF4	IF3	IF2	IF1	IF0

Table 22 Description of 3rd data byte bits

BIT	SYMBOL	DESCRIPTION
7	STEREO	Stereo indication: if STEREO = 1 then stereo reception; if STEREO = 0 then mono reception
6 to 0	PLL[13:8]	IF counter result

Table 23 Format of 4th data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
LEV3	LEV2	LEV1	LEV0	CI3	CI2	CI1	0

Table 24 Description of 4th data byte bits

BIT	SYMBOL	DESCRIPTION
7 to 4	LEV[3:0]	level ADC output
3 to 1	CI[3:1]	Chip Identification: these bits have to be set to logic 0
0	–	this bit is internally set to logic 0

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Table 25 Format of 5th data byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
0	0	0	0	0	0	0	0

Table 26 Description of 5th data byte bits

BIT	SYMBOL	DESCRIPTION
7 to 0	–	reserved for future extensions; these bits are internally set to logic 0

8.6 Bus timing

Table 27 Digital levels and timing

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Digital inputs					
V_{IH}	HIGH-level input voltage		$0.45V_{CCD}$	–	V
V_{IL}	LOW-level input voltage		–	$0.2V_{CCD}$	V
Digital outputs					
$I_{sink(L)}$	LOW-level sink current		500	–	μA
V_{OL}	LOW-level output voltage	$I_{OL} = 500 \mu A$	–	450	mV
Timing					
f_{clk}	clock input frequency	I ² C-bus enabled	–	400	kHz
		3-wire bus enabled	–	1	MHz
t_{HIGH}	clock HIGH time	I ² C-bus enabled	1	–	μs
		3-wire bus enabled	300	–	ns
t_{LOW}	clock LOW time	I ² C-bus enabled	1	–	μs
		3-wire bus enabled	300	–	ns
$t_{W(write)}$	pulse width for write enable	3-wire bus enabled	1	–	μs
$t_{W(read)}$	pulse width for read enable	3-wire bus enabled	1	–	μs
$t_{su(clk)}$	clock set-up time	3-wire bus enabled	300	–	ns
$t_{h(out)}$	read mode data output hold time	3-wire bus enabled	10	–	ns
$t_{d(out)}$	read mode output delay time	3-wire bus enabled	–	100	ns
$t_{su(write)}$	write mode set-up time	3-wire bus enabled	100	–	ns
$t_{h(write)}$	write mode hold time	3-wire bus enabled	100	–	ns

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9 LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{VCOTANK1}	VCO tuned circuit output voltage 1		−0.3	+8	V
V _{VCOTANK2}	VCO tuned circuit output voltage 2		−0.3	+8	V
V _{CCD}	digital supply voltage		−0.3	+5	V
V _{CCA}	analog supply voltage		−0.3	+8	V
T _{stg}	storage temperature		−55	+150	°C
T _{amb}	ambient temperature		−40	+85	°C
V _{es}	electrostatic handling voltage for all pins except pin DATA	note 1	−200	+200	V
		note 2	−2000	+2000	V
	for pin DATA	note 1	−150	+200	V
		note 2	−2000	+2000	V

Notes

- Machine model (R = 0 Ω, C = 200 pF).
- Human body model (R = 1.5 kΩ, C = 100 pF).

10 THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	29	K/W

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11 DC CHARACTERISTICS

$V_{CCA} = V_{VCOTANK1} = V_{VCOTANK2} = V_{CCD} = 2.7\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply voltages						
V_{CCA}	analog supply voltage		2.5	3.0	5.0	V
$V_{CC(VCO)}$	voltage controlled oscillator supply voltage		2.5	3.0	5.0	V
V_{CCD}	digital supply voltage		2.5	3.0	5.0	V
Supply currents						
I_{CCA}	analog supply current	operating				
		$V_{CCA} = 3\text{ V}$	6.0	8.4	10.5	mA
		$V_{CCA} = 5\text{ V}$	6.2	8.6	10.7	mA
		standby mode				
$I_{CC(VCO)}$	voltage controlled oscillator supply current	$V_{CCA} = 3\text{ V}$	–	3	6	μA
		$V_{CCA} = 5\text{ V}$	–	3.2	6.2	μA
		operating				
		$V_{VCOTANK1} = V_{VCOTANK2} = 3\text{ V}$	560	750	940	μA
I_{CCD}	digital supply current	$V_{VCOTANK1} = V_{VCOTANK2} = 5\text{ V}$	570	760	950	μA
		standby mode				
		$V_{VCOTANK1} = V_{VCOTANK2} = 3\text{ V}$	–	1	2	μA
		$V_{VCOTANK1} = V_{VCOTANK2} = 5\text{ V}$	–	1.2	2.2	μA
I_{CCD}	digital supply current	operating				
		$V_{CCD} = 3\text{ V}$	2.1	3.0	3.9	mA
		$V_{CCD} = 5\text{ V}$	2.25	3.15	4.05	mA
		standby mode; $V_{CCD} = 3\text{ V}$				
		bus enable line HIGH	30	56	80	μA
		bus enable line LOW	11	19	26	μA
		standby mode; $V_{CCD} = 5\text{ V}$				
		bus enable line HIGH	50	78	105	μA
		bus enable line LOW	20	33	45	μA

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
DC operating points						
V _{CPOUT}	unloaded DC voltage		0.1	–	V _{CC(VCO)} – 0.1	V
V _{XTAL1}		data byte 4 bit 4 = 1	1.64	1.72	1.8	V
		data byte 4 bit 4 = 0	1.68	1.75	1.82	V
V _{XTAL2}		data byte 4 bit 4 = 1	1.64	1.72	1.8	V
		data byte 4 bit 4 = 0	1.68	1.75	1.82	V
V _{PHASEFIL}			0.4	1.2	V _{CCA} – 0.4	V
V _{PILFIL}			0.65	0.9	1.3	V
V _{VAFL}		f _{RF} = 98 MHz; V _{RF} = 1 mV	720	850	940	mV
V _{VAFR}		f _{RF} = 98 MHz; V _{RF} = 1 mV	720	850	940	mV
V _{TMUTE}		V _{RF} = 0 V	1.5	1.65	1.8	V
V _{MPXO}		f _{RF} = 98 MHz; V _{RF} = 1 mV	680	815	950	mV
V _{Vref}			1.45	1.55	1.65	V
V _{TIFC}			1.34	1.44	1.54	V
V _{LIMDEC1}			1.86	1.98	2.1	V
V _{LIMDEC2}			1.86	1.98	2.1	V
V _{Igain}			480	530	580	mV
V _{RFI1}			0.93	1.03	1.13	V
V _{RFI2}			0.93	1.03	1.13	V
V _{TAGC}		V _{RF} = 0 V	1	1.57	2	V

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12 AC CHARACTERISTICS

$V_{CCA} = V_{VCOTANK1} = V_{VCOTANK2} = V_{CCD} = 2.7\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; measured in the circuit of Fig.7; all AC values are given in RMS; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Voltage controlled oscillator						
f_{osc}	oscillator frequency		150	–	217	MHz
Crystal oscillator						
CIRCUIT INPUT: PIN XTAL2						
$V_{i(osc)}$	oscillator input voltage	oscillator externally clocked	140	–	350	mV
R_i	input resistance	oscillator externally clocked				
		data byte 4 bit 4 = 0	2	3	4	k Ω
		data byte 4 bit 4 = 1	230	330	430	k Ω
C_i	input capacitance	oscillator externally clocked				
		data byte 4 bit 4 = 0	3.9	5.6	7.3	pF
		data byte 4 bit 4 = 1	5	6	7	pF
CRYSTAL: 32.768 kHz						
f_r	series resonance frequency	data byte 4 bit 4 = 1	–	32.768	–	kHz
$\Delta f/f_r$	frequency deviation		-20×10^{-6}	–	$+20 \times 10^{-6}$	
C_0	shunt capacitance		–	–	3.5	pF
R_s	series resistance		–	–	80	k Ω
$\Delta f_r/f_r(25\text{ }^{\circ}\text{C})$	temperature drift	$-10\text{ }^{\circ}\text{C} < T_{amb} < +60\text{ }^{\circ}\text{C}$	-50×10^{-6}	–	$+50 \times 10^{-6}$	
CRYSTAL: 13 MHz						
f_r	series resonance frequency	data byte 4 bit 4 = 0	–	13	–	MHz
$\Delta f/f_r$	frequency deviation		-30×10^{-6}	–	$+30 \times 10^{-6}$	
C_0	shunt capacitance		–	–	4.5	pF
C_{mot}	motional capacitance		1.5	–	3.0	fF
R_s	series resistance		–	–	100	Ω
$\Delta f_r/f_r(25\text{ }^{\circ}\text{C})$	temperature drift	$-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$	-30×10^{-6}	–	$+30 \times 10^{-6}$	
Synthesizer						
PROGRAMMABLE DIVIDER						
N_{prog}	programmable divider ratio	data byte 1 = XX111111; data byte 2 = 11111111	–	–	8191	
		data byte 1 = XX010000; data byte 2 = 00000000	2048	–	–	
ΔN_{step}	programmable divider step size		–	1	–	
REFERENCE FREQUENCY DIVIDER						
N_{ref}	crystal oscillator divider ratio	data byte 4 bit 4 = 0	–	260	–	
		data byte 5 bit 7 = 1; data byte 4 bit 4 = 0	–	130	–	
		data byte 4 bit 4 = 1	–	1	–	

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CHARGE PUMP: PIN CPOUT						
I _{sink}	charge pump peak sink current	0.2 V < V _{CPOUT} < V _{VCOTANK2} – 0.2 V; f _{VCO} > f _{ref} × N _{prog}	–	0.5	–	μA
I _{source}	charge pump peak source current	0.2 V < V _{CPOUT} < V _{VCOTANK2} – 0.2 V; f _{VCO} < f _{ref} × N _{prog}	–	–0.5	–	μA
IF counter						
V _{RF}	RF input voltage for correct IF count		–	12	18	μV
N _{IF}	IF counter length		–	7	–	bit
N _{precount}	IF counter prescaler ratio		–	64	–	
T _{count(IF)}	IF counter period	f _{xtal} = 32.768 kHz	–	15.625	–	ms
		f _{xtal} = 13 MHz	–	15.754	–	ms
RES _{count(IF)}	IF counter resolution	f _{xtal} = 32.768 kHz	–	4.096	–	kHz
		f _{xtal} = 13 MHz	–	4.0625	–	kHz
IF _{count}	IF counter result for search tuning stop	f _{xtal} = 32.768 kHz	31	–	3E	HEX
		f _{xtal} = 13 MHz	32	–	3D	HEX
Pins DATA, CLOCK, WRITE/READ, BUSMODE and BUSENABLE						
R _i	input resistance		10	–	–	MΩ
Software programmable ports						
PIN SWPORT1						
I _{sink(max)}	maximum sink current	data byte 4 bit 0 = 0; data byte 5 bit 0 = 0; V _{SWPORT1} < 0.5 V	500	–	–	μA
I _{leak(max)}	maximum leakage current	data byte 4 bit 0 = 1; V _{SWPORT1} < 5 V	–1	–	+1	μA
PIN SWPORT2						
I _{sink(max)}	maximum sink current	data byte 5 bit 7 = 0; V _{SWPORT1} < 0.5 V	500	–	–	μA
I _{leak(max)}	maximum leakage current	data byte 5 bit 1 = 1; V _{SWPORT1} < 5 V	–1	–	+1	μA
FM signal channel						
FM RF INPUT						
R _i	input resistance at pins RFI1 and RFI2 to RFGND		75	100	125	Ω
C _i	input capacitance at pins RFI1 and RFI2 to RFGND		2.5	4	6	pF

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{RF}	RF sensitivity input voltage	$f_{RF} = 76$ to 108 MHz; $\Delta f = 22.5$ kHz; $f_{mod} = 1$ kHz; (S+N)/N = 26 dB; de-emphasis = 75 μ s; $B_{AF} = 300$ Hz to 15 kHz	–	2	3.5	μ V
$IP3_{in}$	in-band 3rd-order intercept point related to $V_{RF1-RF2}$ (peak value)	$\Delta f_1 = 200$ kHz; $\Delta f_2 = 400$ kHz; $f_{tune} = 76$ to 108 MHz	81	84	–	dB μ V
$IP3_{out}$	out-band 3rd-order intercept point related to $V_{RF1-RF2}$ (peak value)	$\Delta f_1 = 4$ MHz; $\Delta f_2 = 8$ Hz; $f_{tune} = 76$ to 108 MHz	82	85	–	dB μ V
RF AGC						
V_{RF1}	RF input voltage for start of AGC	$f_{RF1} = 93$ MHz; $f_{RF2} = 98$ MHz; $V_{RF2} = 50$ dB μ V; $\left \frac{\Delta V_{TMUTE}}{V_{RF1}} \right < \frac{14 \text{ mV}}{3 \text{ dB}\mu\text{V}}$; note 1	66	72	78	dB μ V
IF filter						
f_{IF}	IF filter centre frequency		215	225	235	kHz
B_{IF}	IF filter bandwidth		85	94	102	kHz
S_{+200}	HIGH side 200 kHz selectivity	$\Delta f = +200$ kHz; $f_{tune} = 76$ to 108 MHz; note 2	39	43	–	dB
S_{-200}	LOW side 200 kHz selectivity	$\Delta f = -200$ kHz; $f_{tune} = 76$ to 108 MHz; note 2	32	36	–	dB
S_{+100}	HIGH side 100 kHz selectivity	$\Delta f = +100$ kHz; $f_{tune} = 76$ to 108 MHz; note 2	8	12	–	dB
S_{-100}	LOW side 100 kHz selectivity	$\Delta f = -100$ kHz; $f_{tune} = 76$ to 108 MHz; note 2	8	12	–	dB
IR	image rejection	$f_{tune} = 76$ to 108 MHz; $V_{RF} = 50$ dB μ V	24	30	–	dB
FM IF level detector and mute voltage						
V_{RF}	RF input voltage for start of level ADC	read mode data byte 4 bit 4 = 1	2	3	5	μ V
ΔV_{step}	level ADC step size		2	3	5	dB
PIN TMUTE						
V_{level}	level output DC voltage	$V_{RF} = 0$ μ V	1.55	1.65	1.80	V
		$V_{RF} = 3$ μ V	1.60	1.70	1.85	V
$V_{level(slope)}$	slope of level voltage	$V_{RF} = 10$ to 500 μ V	150	165	180	$\frac{\text{mV}}{20 \text{ dB}}$
R_o	output resistance		280	400	520	k Ω

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
FM demodulator: pin MPXO						
V_{MPXO}	demodulator output voltage	$V_{RF} = 1 \text{ mV}$; $L = R$; $\Delta f = 22.5 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$; $B_{AF} = 300 \text{ Hz to } 15 \text{ kHz}$	60	75	90	mV
(S+N)/N	maximum signal plus noise-to-noise ratio	$V_{RF} = 1 \text{ mV}$; $L = R$; $\Delta f = 22.5 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$; $B_{AF} = 300 \text{ Hz to } 15 \text{ kHz}$	54	60	–	dB
THD	total harmonic distortion	$V_{RF} = 1 \text{ mV}$; $L = R$; $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$	–	0.5	1.5	%
α_{AM}	AM suppression	$V_{RF} = 300 \mu\text{V}$; $L = R$; $\Delta f = 22.5 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; $m = 0.3$; de-emphasis = $75 \mu\text{s}$; $B_{AF} = 300 \text{ Hz to } 15 \text{ kHz}$	40	–	–	dB
R_o	demodulator output resistance		–	–	500	Ω
I_{sink}	demodulator output sink current		–	–	30	μA
Soft mute						
V_{RF}	RF input voltage for soft mute start	$\alpha_{mute} = 3 \text{ dB}$; data byte 4 bit 3 = 1	3	5	10	μV
α_{mute}	mute attenuation	$V_{RF} = 1 \mu\text{V}$; $L = R$; $\Delta f = 22.5 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$; $B_{AF} = 300 \text{ Hz to } 15 \text{ kHz}$; data byte 4 bit 3 = 1	10	20	30	dB
MPX decoder						
V_{AFL} ; V_{AFR}	left and right audio frequency output voltage	$V_{RF} = 1 \text{ mV}$; $L = R$; $\Delta f = 22.5 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$	60	75	90	mV
R_{AFL} ; R_{AFR}	left and right audio frequency output resistance		–	–	50	Ω
$I_{sink(AFL)}$; $I_{sink(AFR)}$	left and right audio frequency output sink current		170	–	–	μA
$V_{MPXIN(max)}$	input overdrive margin	THD < 3%	4	–	–	dB
V_{AFL}/V_{AFR}	left and right audio frequency output voltage difference	$V_{RF} = 1 \text{ mV}$; $L = R$; $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$	–1	–	+1	dB
$\alpha_{cs(stereo)}$	stereo channel separation	$V_{RF} = 1 \text{ mV}$; $R = L = 0$ or $R = 0$ and $L = 1$ including 9% pilot; $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; data byte 3 bit 3 = 0; data byte 4 bit 1 = 1	24	30	–	dB

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
(S+N)/N	maximum signal plus noise-to-noise ratio	$V_{RF} = 1 \text{ mV}$; $L = R$; $\Delta f = 22.5 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$; $B_{AF} = 300 \text{ Hz to } 15 \text{ kHz}$	54	60	–	dB
THD	total harmonic distortion	$V_{RF} = 1 \text{ mV}$; $L = R$; $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$	–	0.4	1	%
α_{pilot}	pilot suppression measured at pins V_{AFL} and V_{AFR}	related to $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; de-emphasis = $75 \mu\text{s}$	40	50	–	dB
Δf_{pilot}	stereo pilot frequency deviation	$V_{RF} = 1 \text{ mV}$; read mode; data byte 3 bit 7 = 1 bit 7 = 0	– 1	3.6 3	5.8 –	kHz kHz
$\frac{\Delta f_{pilot1}}{\Delta f_{pilot2}}$	pilot switch hysteresis	$V_{RF} = 1 \text{ mV}$	2	–	–	dB
HIGH CUT CONTROL						
TC_{de-em}	de-emphasis time constant	$V_{RF} = 1 \text{ mV}$				
		data byte 5 bit 2 = 0	38	50	62	μs
		data byte 5 bit 2 = 1	57	75	93	μs
		$V_{RF} = 1 \mu\text{V}$				
		data byte 5 bit 2 = 0	114	150	186	μs
		data byte 5 bit 2 = 1	171	225	279	μs
MONO TO STEREO BLEND CONTROL						
$\alpha_{cs(stereo)}$	stereo channel separation	$V_{RF} = 45 \mu\text{V}$; $R = L = 0$ or $R = 0$ and $L = 1$ including 9% pilot; $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; data byte 3 bit 3 = 0; data byte 4 bit 1 = 1	4	10	16	dB
MONO TO STEREO SWITCHED						
$\alpha_{cs(stereo)}$	stereo channel separation switching from mono to stereo with increasing RF input level	$V_{RF} = 1 \mu\text{V}$; $R = L = 0$ or $R = 0$ and $L = 1$ including 9% pilot; $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; data byte 3 bit 3 = 0; data byte 4 bit 1 = 0	24	–	–	dB
$\alpha_{cs(stereo)}$	stereo channel separation switching from stereo to mono with decreasing RF input level	$V_{RF} = 20 \mu\text{V}$; $R = L = 0$ or $R = 0$ and $L = 1$ including 9% pilot; $\Delta f = 75 \text{ kHz}$; $f_{mod} = 1 \text{ kHz}$; data byte 3 bit 3 = 0; data byte 4 bit 1 = 0	–	–	1	dB

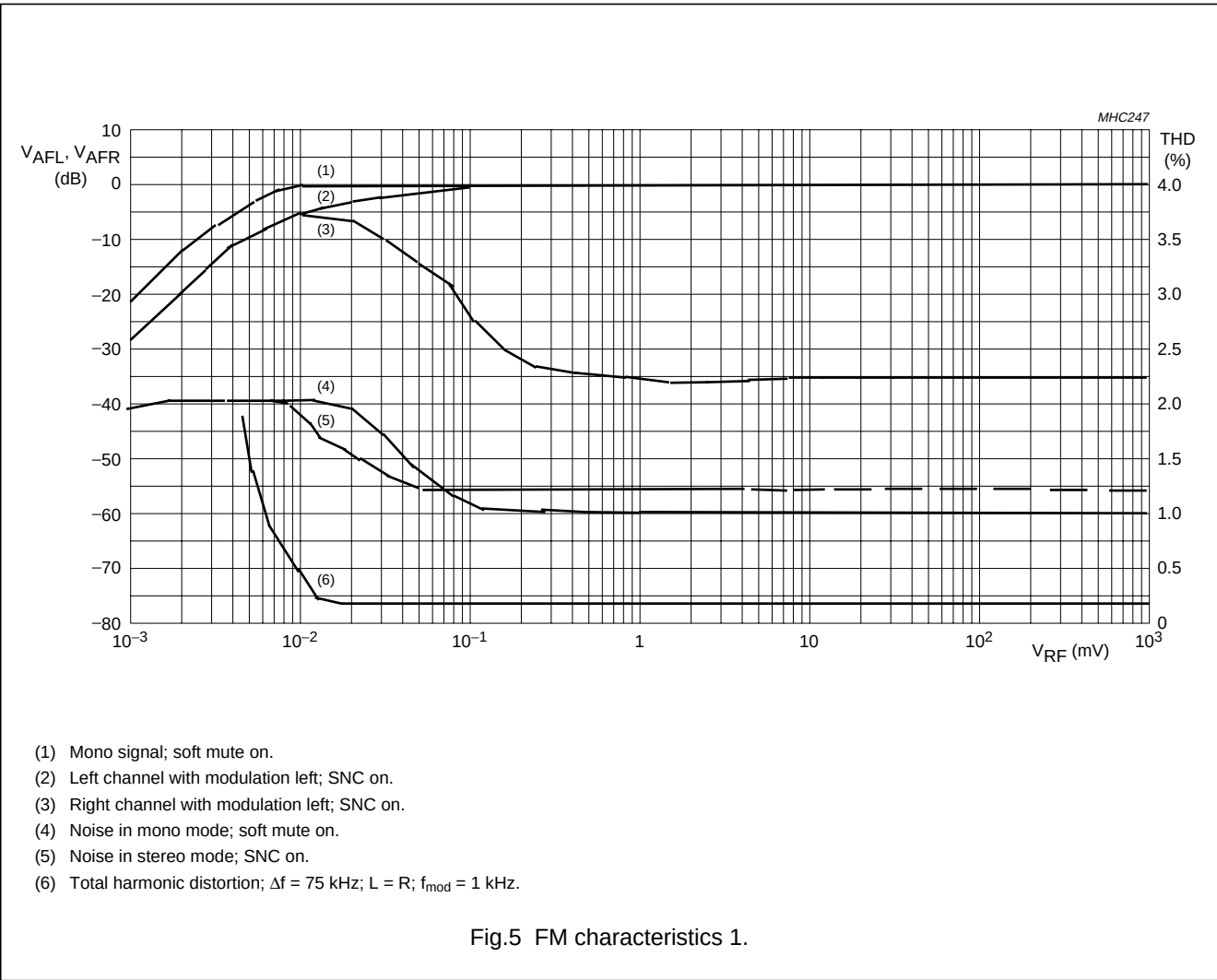
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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BUS-DRIVEN MUTE FUNCTIONS						
<i>Tuning mute</i>						
α_{mute}	V_{AFL} and V_{AFR} muting depth	data byte 1 bit 7 = 1	−60	−	−	dB
$\alpha_{\text{mute(R)}}$	V_{AFR} muting depth	data byte 3 bit 1 = 1	−80	−	−	dB
$\alpha_{\text{mute(L)}}$	V_{AFL} muting depth	data byte 3 bit 2 = 1	−80	−	−	dB

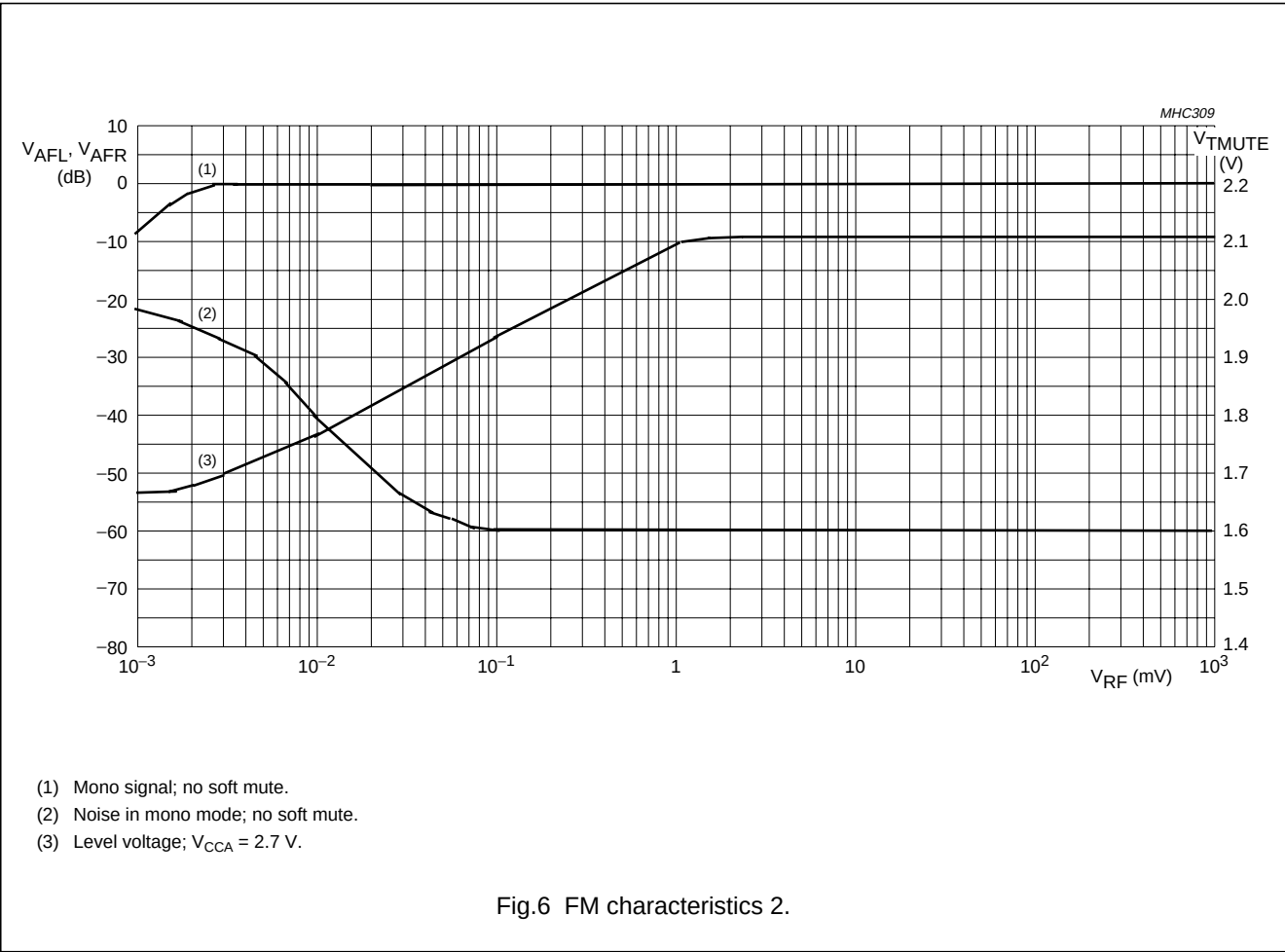
Notes

1. V_{RF} in Fig.7 is replaced by $V_{\text{RF1}} + V_{\text{RF2}}$. The radio is tuned to 98 MHz (HIGH side injection).
2. LOW side and HIGH side selectivity can be switched by changing the mixer from HIGH side to LOW side LO injection.



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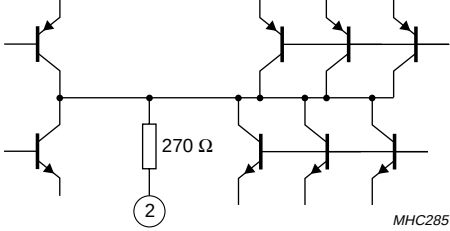
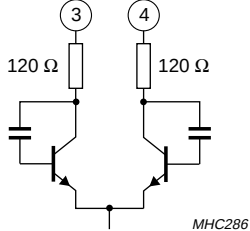
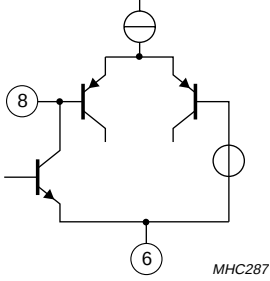
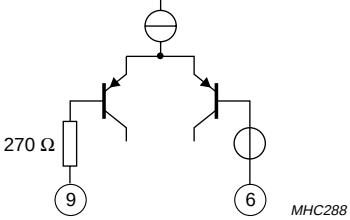
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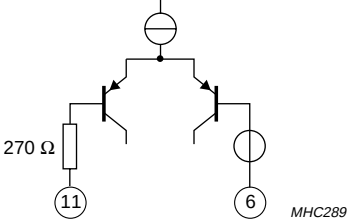
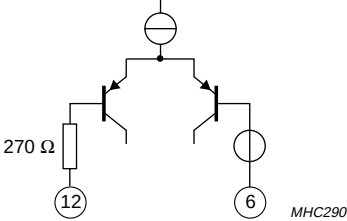
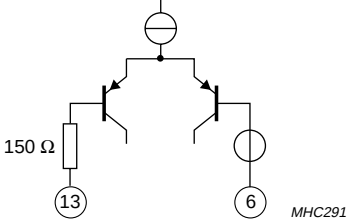
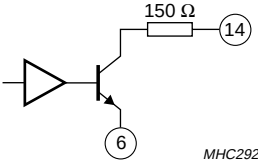
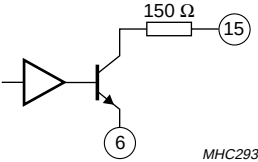
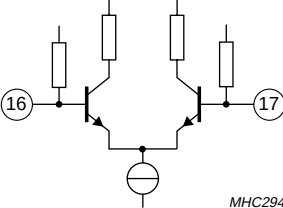
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13 INTERNAL PIN CONFIGURATION

PIN	SYMBOL	EQUIVALENT CIRCUIT
1	n.c.	
2	CPOUT	
3	VCOTANK1	
4	VCOTANK2	
5	V _{CC(VCO)}	
6	DGND	
7	V _{CCD}	
8	DATA	
9	CLOCK	
10	n.c.	

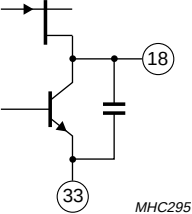
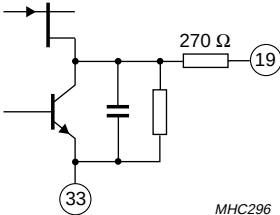
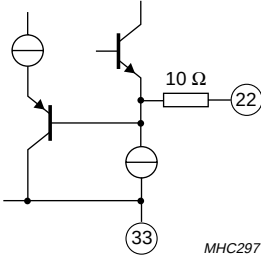
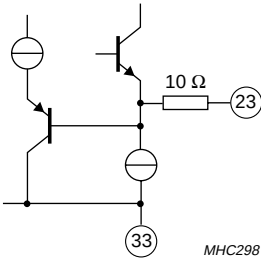
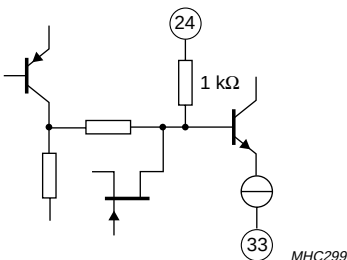
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PIN	SYMBOL	EQUIVALENT CIRCUIT
11	WRITE/READ	 MHC289
12	BUSMODE	 MHC290
13	BUSENABLE	 MHC291
14	SWPORT1	 MHC292
15	SWPORT2	 MHC293
16	XTAL1	 MHC294
17	XTAL2	

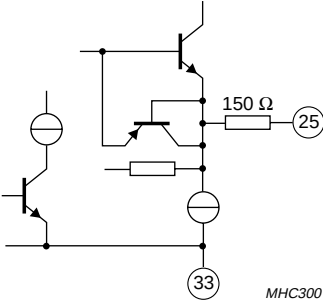
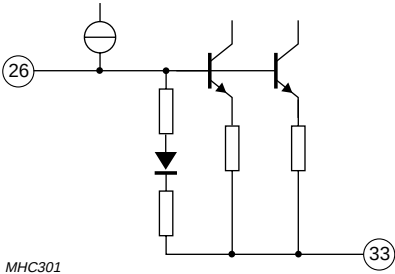
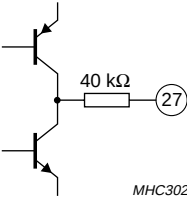
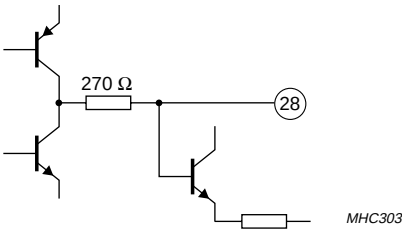
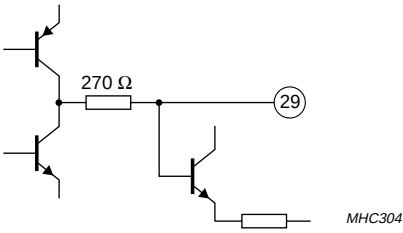
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PIN	SYMBOL	EQUIVALENT CIRCUIT
18	PHASEFIL	
19	PILFIL	
20	n.c.	
21	n.c.	
22	V _{AFL}	
23	V _{AFR}	
24	TMUTE	

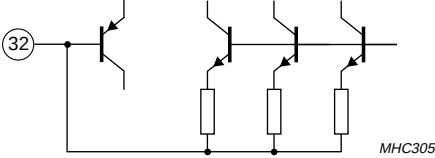
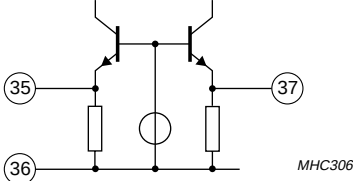
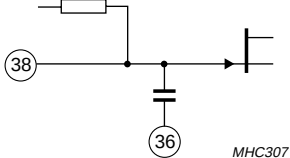
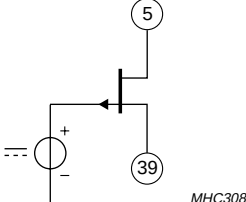
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PIN	SYMBOL	EQUIVALENT CIRCUIT
25	MPXO	 MHC300
26	V _{ref}	 MHC301
27	TIFC	 MHC302
28	LIMDEC1	 MHC303
29	LIMDEC2	 MHC304
30	n.c.	
31	n.c.	

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PIN	SYMBOL	EQUIVALENT CIRCUIT
32	I _{gain}	
33	AGND	
34	V _{CCA}	
35	RFI1	
36	RFGND	
37	RFI2	
38	TAGC	
39	LOOPSW	
40	n.c.	

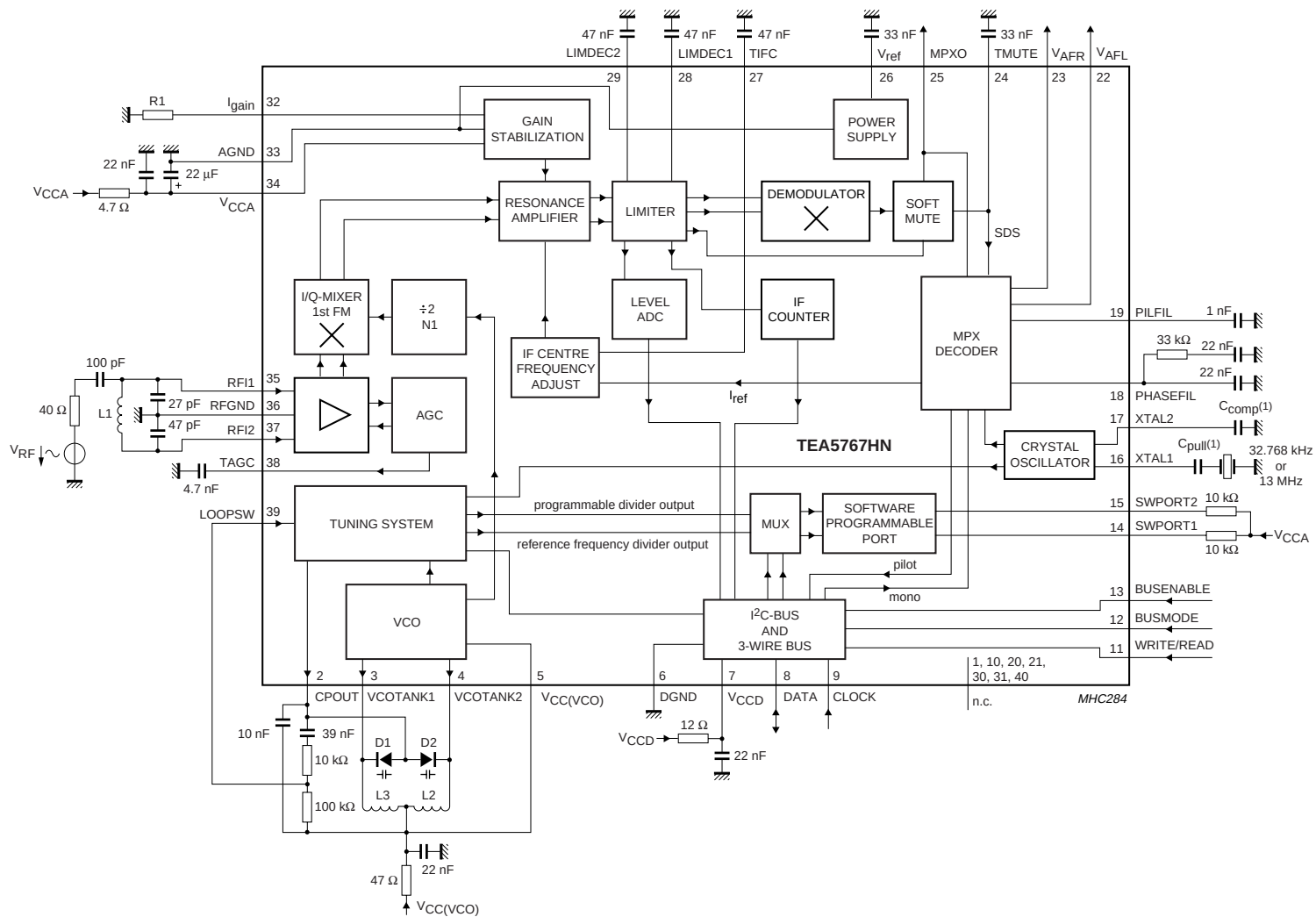
14 APPLICATION INFORMATION

Table 28 Component list for Figs 1 and 7

COMPONENT	PARAMETER	VALUE	TOLERANCE	TYPE	MANUFACTURER
R1	resistor with low temperature coefficient	18 kΩ	±1%	RC12G	Philips
D1 and D2	varicap for VCO tuning	–	–	BB202	Philips
L1	RF band filter coil	120 nH	±2%	Q _{min} = 40	
L2 and L3	VCO coil	33 nH	±2%	Q _{min} = 40	
XTAL13	13 MHz crystal	–	–	NX4025GA	
C _{pull}	pulling capacitor for NX4025GA	10 pF	–		
XTAL32.768	32.768 kHz crystal	–	–		

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(1) C_{comp} and C_{pull} data depends on crystal specification.

Fig.7 Test circuit.

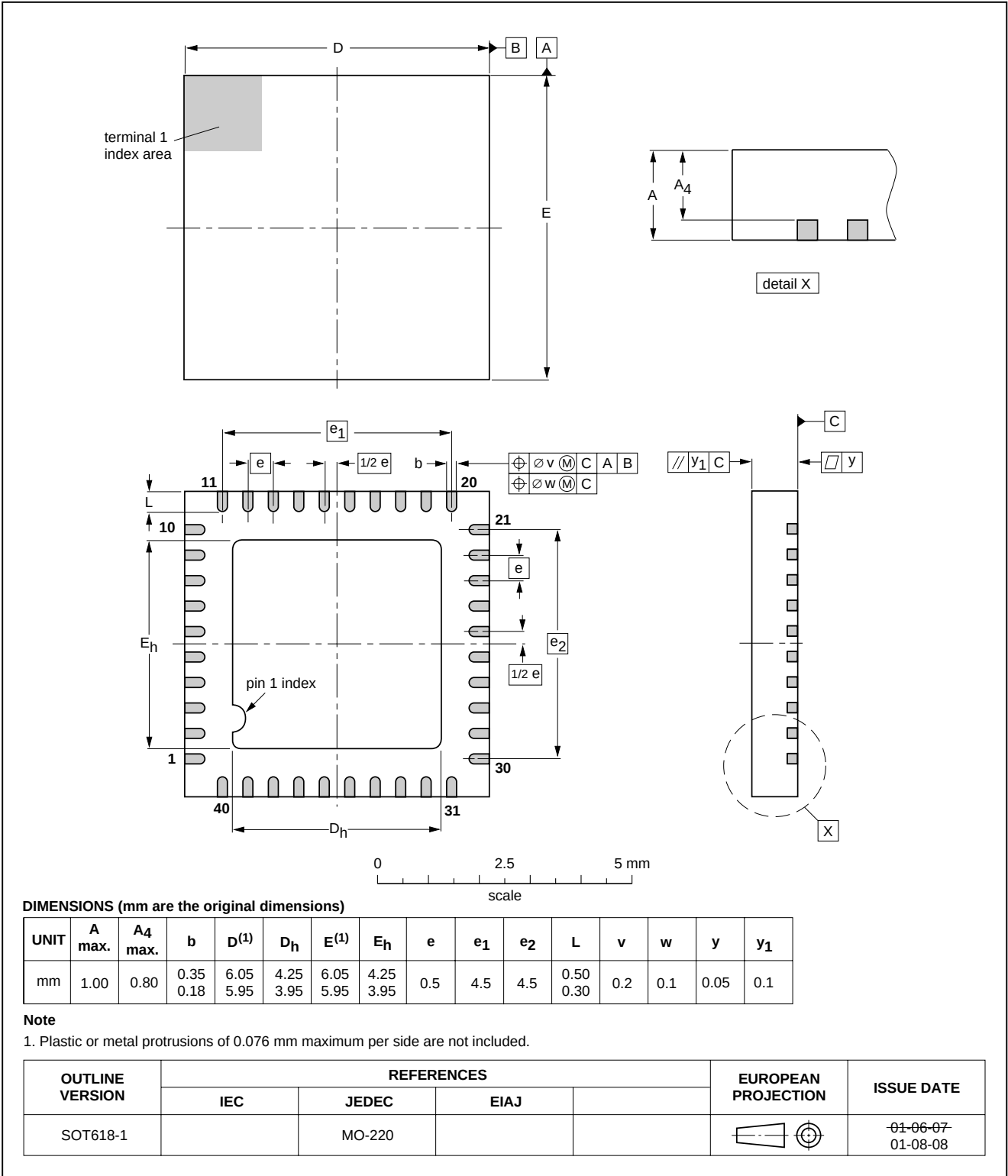
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15 PACKAGE OUTLINE

HVQFN40: plastic, heatsink very thin quad flat package; no leads;
40 terminals; body 6 x 6 x 0.85 mm

SOT618-1



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16 SOLDERING

16.1 Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

16.2 Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

16.3 Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis **must** be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

- For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

16.4 Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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16.5 Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD	
	WAVE	REFLOW ⁽¹⁾
BGA, HBGA, LFBGA, SQFP, TFBGA	not suitable	suitable
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, SMS	not suitable ⁽²⁾	suitable
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable

Notes

1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the “*Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods*”.
2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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